

MM54C00/MM74C00 Quad 2-Input NAND Gate MM54C02/MM74C02 Quad 2-Input NOR Gate MM54C04/MM74C04 Hex Inverter MM54C10/MM74C10 Triple 3-Input NAND Gate MM54C20/MM74C20 Dual 4-Input NAND Gate

General Description

These logic gates employ complementary MOS (CMOS) to achieve wide power supply operating range, low power consumption, high noise immunity and symmetric controlled rise and fall times. With features such as this the 54C/74C logic family is close to ideal for use in digital systems. Function and pin out compatibility with series 54/74 devices minimizes design time for those designers already familiar with the standard 54/74 logic family.

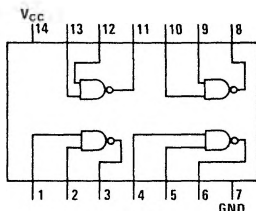
All inputs are protected from damage due to static discharge by diode clamps to V_{CC} and GND.

Features

- Wide supply voltage range 3.0V to 15V
- Guaranteed noise margin 1.0V
- High noise immunity $0.45 V_{CC}$ (typ.)
- Low power consumption 10 nW/package (typ.)
- Low power TTL compatibility fan out of 2 driving 74L

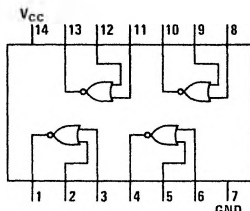
Connection Diagrams

MM54C00/MM74C00



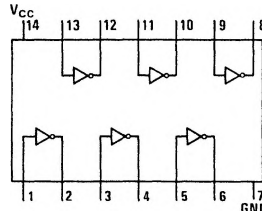
TOP VIEW

MM54C02/MM74C02



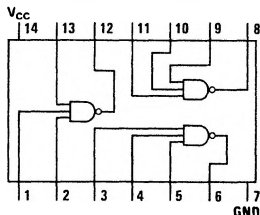
TOP VIEW

MM54C04/MM74C04



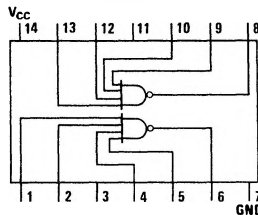
TOP VIEW

MM54C10/MM74C10



TOP VIEW

MM54C20/MM74C20



TOP VIEW

Absolute Maximum Ratings

Voltage at Any Pin	-0.3V to $V_{CC} + 0.3V$
Operating Temperature Range	
54C	-55°C to +125°C
74C	-40°C to +85°C
Storage Temperature Range	-65°C to +150°C
Operating V_{CC} Range	3.0V to 15V
Maximum V_{CC} Voltage	18V
Package Dissipation	500 mW
Lead Temperature (Soldering, 10 seconds)	300°C

DC Electrical Characteristics

Min/max limits apply across the guaranteed temperature range unless otherwise noted.

Parameter	Conditions	Min.	Typ.	Max.	Units
CMOS to CMOS					
$V_{IN(1)}$	Logical "1" Input Voltage	$V_{CC} = 5.0V$ $V_{CC} = 10V$	3.5 8.0		V V
$V_{IN(0)}$	Logical "0" Input Voltage	$V_{CC} = 5.0V$ $V_{CC} = 10V$		1.5 2.0	V V
$V_{OUT(1)}$	Logical "1" Output Voltage	$V_{CC} = 5.0V, I_O = -10\mu A$ $V_{CC} = 10V, I_O = -10\mu A$	4.5 9.0		V V
$V_{OUT(0)}$	Logical "0" Output Voltage	$V_{CC} = 5.0V, I_O = +10\mu A$ $V_{CC} = 10V, I_O = +10\mu A$		0.5 1.0	V V
$I_{IN(1)}$	Logical "1" Input Current	$V_{CC} = 15V, V_{IN} = 15V$	0.005	1.0	μA
$I_{IN(0)}$	Logical "0" Input Current	$V_{CC} = 15V, V_{IN} = 0V$	-1.0	-0.005	μA
I_{CC}	Supply Current	$V_{CC} = 15V$	0.01	15	μA
Low Power to CMOS					
$V_{IN(1)}$	Logical "1" Input Voltage	54C, $V_{CC} = 4.5V$ 74C, $V_{CC} = 4.75V$	$V_{CC} - 1.5$ $V_{CC} - 1.5$		V V
$V_{IN(0)}$	Logical "0" Input Voltage	54C, $V_{CC} = 4.5V$ 74C, $V_{CC} = 4.75V$		0.8 0.8	V V
$V_{OUT(1)}$	Logical "1" Output Voltage	54C, $V_{CC} = 4.5V, I_O = -10\mu A$ 74C, $V_{CC} = 4.75V, I_O = -10\mu A$	4.4 4.4		V V
$V_{OUT(0)}$	Logical "0" Output Voltage	54C, $V_{CC} = 4.5V, I_O = +10\mu A$ 74C, $V_{CC} = 4.75V, I_O = +10\mu A$		0.4 0.4	V V
CMOS to Low Power					
$V_{IN(1)}$	Logical "1" Input Voltage	54C, $V_{CC} = 4.5V$ 74C, $V_{CC} = 4.75V$	4.0 4.0		V V
$V_{IN(0)}$	Logical "0" Input Voltage	54C, $V_{CC} = 4.5V$ 74C, $V_{CC} = 4.75V$		1.0 1.0	V V
$V_{OUT(1)}$	Logical "1" Output Voltage	54C, $V_{CC} = 4.5V, I_O = -360\mu A$ 74C, $V_{CC} = 4.75V, I_O = -360\mu A$	2.4 2.4		V V
$V_{OUT(0)}$	Logical "0" Output Voltage	54C, $V_{CC} = 4.5V, I_O = 360\mu A$ 74C, $V_{CC} = 4.75V, I_O = 360\mu A$		0.4 0.4	V V
Output Drive (See 54C/74C Family Characteristics Data Sheet) (short circuit current)					
I_{SOURCE}	Output Source Current	$V_{CC} = 5.0V, V_{IN(0)} = 0V$ $T_A = 25^\circ C, V_{OUT} = 0V$	-1.75		mA
I_{SOURCE}	Output Source Current	$V_{CC} = 10V, V_{IN(0)} = 0V$ $T_A = 25^\circ C, V_{OUT} = 0V$	-8.0		mA
I_{SINK}	Output Sink Current	$V_{CC} = 5.0V, V_{IN(1)} = 5.0V$ $T_A = 25^\circ C, V_{OUT} = V_{CC}$	1.75		mA
I_{SINK}	Output Sink Current	$V_{CC} = 10V, V_{IN(1)} = 10V$ $T_A = 25^\circ C, V_{OUT} = V_{CC}$	8.0		mA

AC Electrical Characteristics

$T_A = 25^\circ\text{C}$, $C_L = 50\text{ pF}$, unless otherwise specified.

Parameter	Conditions	Min.	Typ.	Max.	Units
MM54C00/MM74C00, MM54C02/MM74C02, MM54C04/MM74C04					
t_{pd0} , t_{pd1}	Propagation Delay Time to Logical "1" or "0" $V_{CC} = 5.0\text{V}$ $V_{CC} = 10\text{V}$		50 30	90 60	ns ns
C_{IN}	Input Capacitance (Note 2)		6.0		pF
C_{PD}	Power Dissipation Capacitance (Note 3) Per Gate or Inverter		12		pF
MM54C10/MM74C10					
t_{pd0} , t_{pd1}	Propagation Delay Time to Logical "1" or "0" $V_{CC} = 5.0\text{V}$ $V_{CC} = 10\text{V}$		60 35	100 70	ns ns
C_{IN}	Input Capacitance (Note 2)		7.0		pF
C_{PD}	Power Dissipation Capacitance (Note 3) Per Gate		18		pF
MM54C20/MM74C20					
t_{pd0} , t_{pd1}	Propagation Delay Time to Logical "1" or "0" $V_{CC} = 5.0\text{V}$ $V_{CC} = 10\text{V}$		70 40	115 80	ns ns
C_{IN}	Input Capacitance (Note 2)		9		pF
C_{PD}	Power Dissipation Capacitance (Note 3) Per Gate		30		pF

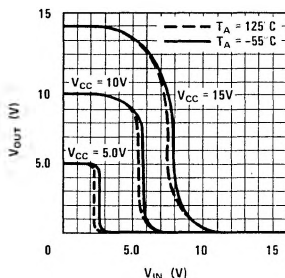
Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.

Note 2: Capacitance is guaranteed by periodic testing.

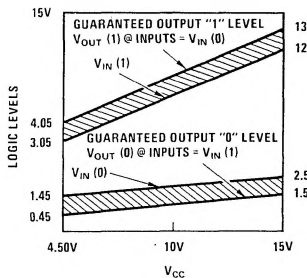
Note 3: C_{PD} determines the no load ac power consumption of any CMOS device. For complete explanation see 54C/74C Family Characteristics application note — AN-90.

Typical Performance Characteristics

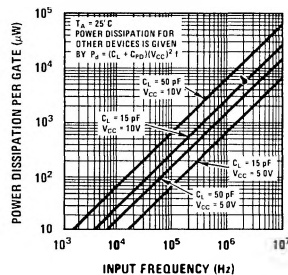
Gate Transfer Characteristics



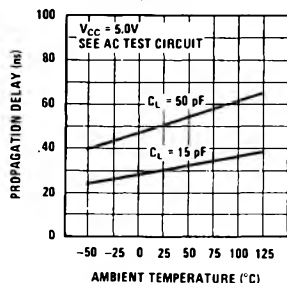
Guaranteed Noise Margin Over Temperature vs V_{CC}



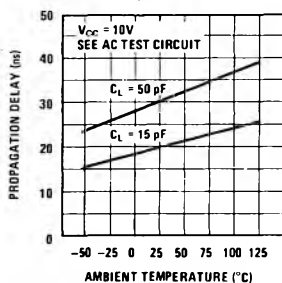
Power Dissipation vs Frequency
MM54C00/MM74C00,
MM54C02/MM74C02,
MM54C04/MM74C04



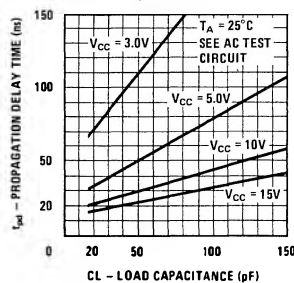
Propagation Delay vs Ambient Temperature
MM54C00/MM74C00,
MM54C02/MM74C02,
MM54C04/MM74C04



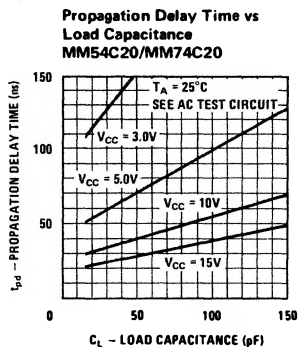
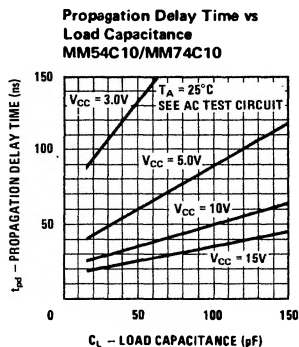
Propagation Delay vs Ambient Temperature
MM54C00/MM74C00,
MM54C02/MM74C02,
MM54C04/MM74C04



Propagation Delay Time vs Load Capacitance
MM54C00/MM74C00,
MM54C02/MM74C02,
MM54C04/MM74C04

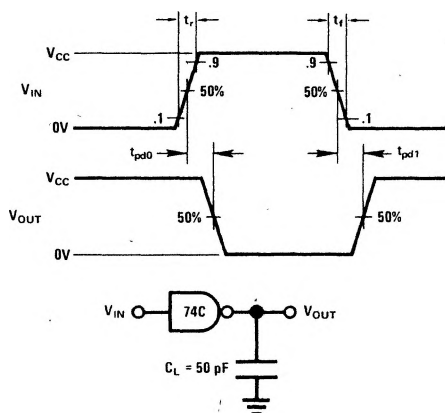


Typical Performance Characteristics (Cont'd)



Switching Time Waveforms and AC Test Circuits

CMOS to CMOS



NOTE: DELAYS MEASURED WITH INPUT $t_r, t_f \leq 20\text{ ns}$.